

Natalia V Morozova

List of Publications by Year in descending order

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citing authors

#	ARTICLE	IF	CITATIONS
1	Strategies and challenges of high-pressure methods applied to thermoelectric materials. Journal of Applied Physics, 2019, 125, .	1.1	46
2	A Hard Oxide Semiconductor with A Direct and Narrow Bandgap and Switchable p-n Electrical Conduction. Advanced Materials, 2014, 26, 8185-8191.	11.1	44
3	Enhanced power factor and high-pressure effects in (Bi,Sb) ₂ (Te,Se) ₃ thermoelectrics. Applied Physics Letters, 2015, 106, .	1.5	41
4	Thermoelectric Properties of Compressed Titanium and Zirconium Trichalcogenides. Journal of Physical Chemistry C, 2018, 122, 14362-14372.	1.5	39
5	Significant enhancement of thermoelectric properties and metallization of Al-doped Mg ₂ Si under pressure. Journal of Applied Physics, 2014, 115, .	1.1	34
6	Smart silicon: Switching between p and n-conduction under compression. Applied Physics Letters, 2012, 101, 062107.	1.5	23
7	Colossal tuning of an energy gap in Sn ₂ P ₂ S ₆ under pressure. Applied Physics Letters, 2011, 99, .	1.5	19
8	Raman spectroscopy of ferroelectric Sn ₂ P ₂ S ₆ under high pressure up to 40 GPa: Phase transitions and metallization. Journal of Applied Physics, 2013, 113, .	1.1	19
9	Features and regularities in behavior of thermoelectric properties of rare-earth, transition, and other metals under high pressure up to 20 GPa. Journal of Applied Physics, 2015, 118, .	1.1	18
10	Stress-controlled thermoelectric module for energy harvesting and its application for the significant enhancement of the power factor of Bi ₂ Te ₃ -based thermoelectrics. Journal Physics D: Applied Physics, 2018, 51, 025501. https://doi.org/10.1088/1361-6461/aa9111	1.3	18
11	Nanostructuring, <i>in situ</i> electronic tuning of the electronic and vibrational properties of Sn ₂ P ₂ S ₆ and Pb ₂ P ₂ S ₆ crystals and their metallization under high pressure. Dalton Transactions, 2017, 46, 4245-4258.	1.1	17
12	Tuning the electronic and vibrational properties of Sn ₂ P ₂ S ₆ and Pb ₂ P ₂ S ₆ crystals and their metallization under high pressure. Dalton Transactions, 2017, 46, 4245-4258.	1.6	17
13	Controlling the thermoelectric power of silicon-germanium alloys in different crystalline phases by applying high pressure. CrystEngComm, 2020, 22, 5416-5435.	1.3	17
14	Dramatic Changes in Thermoelectric Power of Germanium under Pressure: Printing p Junctions by Applied Stress. Scientific Reports, 2017, 7, 44220.	1.6	16
15	Similar behavior of thermoelectric properties of lanthanides under strong compression up to 20 GPa. Journal of Applied Physics, 2012, 111, 112624.	1.1	13
16	Structural and Magnetic Transitions in CaCo ₃ V ₄ O ₁₂ Perovskite at Extreme Conditions. Inorganic Chemistry, 2017, 56, 6251-6263.	1.9	12
17	Electronic transport properties of MFe ₂ As ₂ (M = Ca, Eu, Sr) at ambient and high pressures up to 20 GPa. Superconductor Science and Technology, 2015, 28, 125010.	1.8	10
18	Giant Room-Temperature Power Factor in p-type Thermoelectric SnSe under High Pressure. Advanced Science, 2022, 9, e2103720.	5.6	7

#	ARTICLE	IF	CITATIONS
19	On the Power Factor of Bismuth-Telluride-Based Alloys near Topological Phase Transitions at High Pressures. <i>Semiconductors</i> , 2019, 53, 732-736.	0.2	6
20	Electrical resistivity and Hall effect in lanthanum monobismuthide in magnetic fields to 13 T. <i>Physics of the Solid State</i> , 2015, 57, 2369-2372.	0.2	5
21	Colossal enhancement of the thermoelectric power factor in stress-released orthorhombic phase of SnTe. <i>Applied Physics Letters</i> , 2021, 118, 103903.	1.5	5
22	Colossal variations in the thermopower and ρ conductivity switching in topological tellurides under pressure. <i>Journal of Applied Physics</i> , 2020, 128, .	1.1	5
23	Stress-controlled ρ conductivity switch based on intercalated ZrTe ₂ . <i>Applied Physics Letters</i> , 2021, 119, 053103.	1.5	4
24	Structural Stability and Properties of Marokite-Type $\text{Î}^3\text{-Mn}_{3}\text{O}_{4}$. <i>Inorganic Chemistry</i> , 2021, 60, 13440-13452.	1.9	4
25	Synthesis of Ilmenite-type $\text{Î}^{\mu}\text{-Mn}_{2}\text{O}_{3}$ and Its Properties. <i>Inorganic Chemistry</i> , 2021, 60, 13348-13358.	1.9	4
26	High-pressure study of the thermoelectric properties of various oxides (ZnO,) $\text{Tj ETQq0 0 0 rgBT /Overlock 10 Tf 50 467 Td (Ti}_{2}$ compounds. <i>Physica Status Solidi (B): Basic Research</i> , 2013, 250, 741-745.	0.7	3
27	Thermoelectric properties of TmTe under pressure up to 20 GPa. <i>Physics of the Solid State</i> , 2014, 56, 937-940.	0.2	3
28	Semiconductor-metal phase transition in LaBi under high pressure. <i>Physics of the Solid State</i> , 2015, 57, 1639-1641.	0.2	3
29	Unconventional Electronic Properties of Mg_{2}Si Thermoelectrics Revealed by Fast-Neutron-Irradiation Doping. <i>Journal of Physical Chemistry C</i> , 2016, 120, 9692-9701.	1.5	3
30	Perovskites: A Hard Oxide Semiconductor with A Direct and Narrow Bandgap and Switchable ρ Electrical Conduction (<i>Adv. Mater.</i> 48/2014). <i>Advanced Materials</i> , 2014, 26, 8184-8184.	11.1	1
31	Investigation of the thermopower of thulium monoselenide under a pressure to 24 GPa. <i>Physics of the Solid State</i> , 2014, 56, 1766-1768.	0.2	0
32	Thermopower of lanthanum monochalcogenides subjected to uniform compression up to 22 GPa. <i>Technical Physics</i> , 2015, 60, 469-470.	0.2	0